3.2 Ω, Fast Switching Speed, +12 V / +5 V / +3 V / ± 5 V, 4- / 8-Channel Analog Multiplexers

DESCRIPTION

The DG9408E, DG9409E uses BiCMOS wafer fabrication technology that allows the DG9408E, DG9409E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with ± 3 V to ± 8 V.

The DG9408E is an 8-channel single-ended analog multiplexer designed to connect one of eight inputs to a common output as determined by a 3-bit binary address (A_0, A_1, A_2). The DG9409E is a dual 4-channel differential analog multiplexer designed to connect one of four differential inputs to a common dual output as determined by its 2-bit binary address (A_0, A_1). Break-before-make switching action to protect against momentary crosstalk between adjacent channels.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. The DG9408E, DG9409E are offered in a QFN package that has a nickel-palladium-gold device terminations and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all the JEDEC® standards for reflow and MSL ratings.

FEATURES

- 3 V to 16 V single supply or ± 3 V to ± 8 V dual supply operation
- Low on-resistance - R_{ON}: 3.2 Ω typ.
- Fast switching: t_{ON} - 36 ns, t_{OFF} - 24 ns
- Break-before-make guaranteed
- Low leakage
- TTL, CMOS, LV logic (3 V) compatible
- 2500 V ESD protection (HBM)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

HALOGEN FREE

BENEFITS

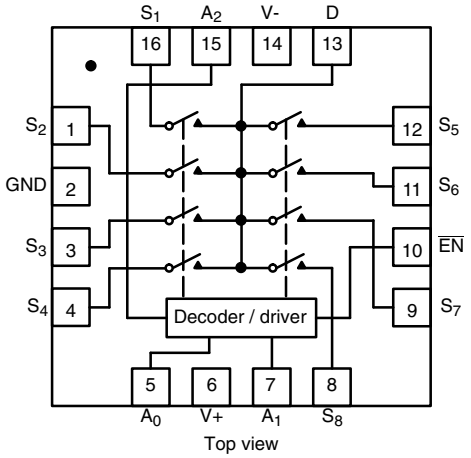
- Fast switching speed
- Low switch resistance
- Wide operation voltage range
- Simple logic interface

APPLICATIONS

- Automatic test equipment
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems

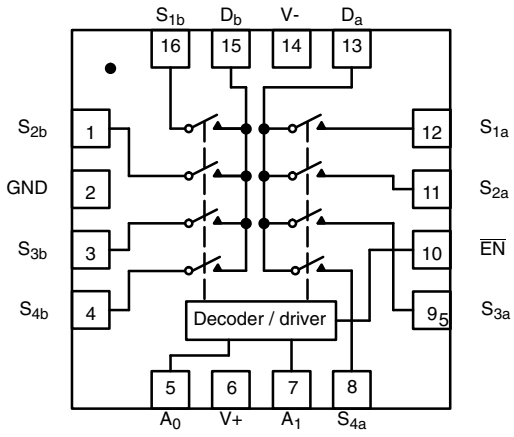
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG9408E
QFN16



Top view

DG9409E
QFN16



Top view

Note

- QFN16 package central exposed pad has no electrical connection inside the chip. It can be connected GND, V+, V-, or left floating

For technical questions, contact: analogswitchtechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TRUTH TABLE AND ORDERING INFORMATION

TRUTH TABLE DG9408E				
A_2	A_1	A_0	$\overline{EN}$	ON SWITCH
X	X	X	1	None
0	0	0	0	1
0	0	1	0	2
0	1	0	0	3
0	1	1	0	4
1	0	0	0	5
1	0	1	0	6
1	1	0	0	7
1	1	1	0	8

TRUTH TABLE DG9409E			
A_1	A_0	$\overline{EN}$	ON SWITCH
X	X	1	None
0	0	0	1
0	1	0	2
1	0	0	3
1	1	0	4

X = do not care

For low and high voltage levels for V_{AX} and $V_{\overline{EN}}$ consult “Digital Control” parameters for specific V+ operation. See specifications tables for:

Single supply 12 V

Dual supply V+ = 5 V, V- = -5 V

Single supply 5 V

Single supply 3 V

ORDERING INFORMATION			
TEMP. RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY
-40 °C to +85 °C	16-pin QFN (4 mm x 4 mm) (variation 1)	DG9408EDN-T1-GE4	Tape and reel, 2500 units
		DG9409EDN-T1-GE4	Tape and reel, 2500 units

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)			
PARAMETER		LIMIT	UNIT
Voltage referenced V+ to V-		-0.3 to +18	V
GND to V-		18	
Digital inputs [a], V_S, V_D		(V-) - 0.3 to (V+) + 0.3	
Current (any terminal except S or D)		30	mA
Continuous current, S or D		100	
Peak current, S or D (pulsed at 1 ms, 10 % duty cycle max.)		200	
Package solder reflow conditions (lead (Pb)-free assembly) [d]	16-pin (4 x 4 mm) QFN	260 +0 / -5	°C
Storage temperature		-65 to +150	
Power dissipation (package) [b], (T_A = 70 °C)	16-pin (4 x 4 mm) QFN [c]	1880	mW
ESD human body model (HBM), per ANSI / ESDA / JEDEC® JS-001		2500	V
Latch up current, per JESD78		400	mA

Notes

a. Signals on SX, DX or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings

b. All leads soldered or welded to PC board

c. Derate 23.5 mW/°C above 70 °C

d. Manual soldering with soldering iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

SPECIFICATIONS (Single Supply 12 V)								
PARAMETER	**SYMBOL**	**TEST CONDITIONS UNLESS OTHERWISE SPECIFIED** V+ = 12 V, ± 10 %, V- = 0 V V_A, $V_{\overline{EN}}$ = 0.8 V or 2.4 V [f]		**TEMP.[b]**	**LIMITS -40 °C to +85 °C**			**UNIT**
					MIN. [c]	**TYP. [d]**	**MAX. [c]**	
Analog Switch								
Analog signal range [e]	V_{ANALOG}			Full	0	-	12	V
On-resistance	R_{ON}	V+ = 10.8 V, V_D = 2 V or 9 V, I_S = 50 mA sequence each switch on		Room	-	3.2	7	Ω
				Full	-		7.5	
R_{ON} match between channels [g]	ΔR_{ON}	V+ = 10.8 V, V_D = 2 V or 9 V, I_S = 50 mA		Room	-	-	3.6	
On-resistance flatness [i]	R_{ON} flatness			Room	-	-	8	
Switch off leakage current	$I_{S(off)}$	$V_{\overline{EN}}$ = 2.4 V, V_D = 11 V or 1 V, V_S = 1 V or 11 V		Room	-2	-	2	nA
				Full	-15	-	15	
	$I_{D(off)}$			Room	-2	-	2	
				Full	-15	-	15	
Channel on leakage current	$I_{D(on)}$	$V_{\overline{EN}}$ = 0 V, V_S = V_D = 1 V or 11 V		Room	-2	-	2	
				Full	-15	-	15	
Digital Control								
Logic high input voltage	V_{INH}			Full	2.4	-	-	V
Logic low input voltage	V_{INL}			Full	-	-	0.8	
Input current	I_{IN}	V_{AX} = $V_{\overline{EN}}$ = 2.4 V or 0.8 V		Full	-1	-	1	µA
Dynamic Characteristics								
Transition time	t_{TRANS}	V_{S1} = 8 V, V_{S8} = 0 V, (DG9408E) V_{S1b} = 8 V, V_{S4b} = 0 V, (DG9409E) see fig. 2		Room	-	40	71	ns
				Full	-	-	75	
Break-before-make time	t_{BBM}	$V_{S(all)}$ = V_{DA} = 5 V see fig. 4		Room	2	20	-	
				Full	-	-	-	
Enable turn-on time	$t_{ON(\overline{EN})}$	V_{AX} = 0 V, V_{S1} = 5 V (DG9408E) V_{AX} = 0 V, V_{S1b} = 5 V (DG9409E) see fig. 3		Room	-	36	70	
				Full	-	-	75	
Enable turn-off time	$t_{OFF(\overline{EN})}$			Room	-	24	44	
				Full	-	-	46	
Charge injection [e]	Q	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω		Room	-	4.5	-	pC
Off isolation [e, h]	OIRR	f = 100 kHz, R_L = 1 kΩ		Room	-	-83	-	dB
Crosstalk [e]	X_{TALK}			Room	-	-89	-	
Source off capacitance [e]	$C_{S(off)}$	f = 1 MHz, V_S = 0 V, $V_{\overline{EN}}$ = 2.4 V	DG9408E	Room	-	17	-	pF
			DG9409E	Room	-	16	-	
Drain off capacitance [e]	$C_{D(off)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 2.4 V	DG9408E	Room	-	134	-	
			DG9409E	Room	-	67	-	
Drain on capacitance [e]	$C_{D(on)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 0 V	DG9408E	Room	-	154	-	
			DG9409E	Room	-	86	-	
Power Supplies								
Power supply current	I+	$V_{\overline{EN}}$ = V_A = 0 V or V+		Room	-	-	1	µA

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

SPECIFICATIONS (Dual Supply V+ = 5 V, V- = -5 V)								
PARAMETER	**SYMBOL**	**TEST CONDITIONS UNLESS OTHERWISE SPECIFIED** V+ = 5 V, V- = -5 V, ± 10 % V_A, $V_{\overline{EN}}$ = 0.8 V or 2 V [f]		**TEMP.** [b]	**LIMITS -40 °C to +85 °C**			**UNIT**
					MIN. [c]	**TYP.** [d]	**MAX.** [c]	
Analog Switch								
Analog signal range [e]	V_{ANALOG}			Full	-5	-	5	V
On-resistance	R_{ON}	V+ = 4.5 V, V- = -4.5 V, V_D = ± 3.5 V, I_S = 50 mA sequence each switch on		Room	-	4	8	Ω
				Full	-	-	8.5	
R_{ON} match between channels [g]	ΔR_{ON}	V+ = 4.5 V, V- = -4.5 V, V_D = ± 3.5 V, I_S = 50 mA		Room	-	-	3.6	
On-resistance flatness [i]	R_{ON} Flatness			Room	-	-	8.2	
Switch off leakage current [a]	$I_{S(off)}$	V+ = 5.5, V- = -5.5 V $V_{\overline{EN}}$ = 2.4 V, V_D = ± 4.5 V, V_S = ± 4.5 V		Room	-2	-	2	nA
				Full	-15	-	15	
	$I_{D(off)}$			Room	-2	-	2	
				Full	-15	-	15	
Channel on leakage current [a]	$I_{D(on)}$	V+ = 5.5 V, V- = -5.5 V $V_{\overline{EN}}$ = 0 V, V_D = ± 4.5 V, V_S = ± 4.5 V		Room	-2	-	2	
				Full	-15	-	15	
Digital Control								
Logic high input voltage	V_{INH}			Full	2	-	-	V
Logic low input voltage	V_{INL}			Full	-	-	0.8	
Input current [a]	I_{IN}	V_{AX} = $V_{\overline{EN}}$ = 2 V or 0.8 V		Full	-1	-	1	µA
Dynamic Characteristics								
Transition time [e]	t_{TRANS}	V_{S1} = 3.5 V, V_{S8} = -3.5 V, (DG9408E) V_{S1b} = 3.5 V, V_{S4b} = -3.5 V, (DG9409E) see fig. 2		Room	-	47	65	ns
				Full	-	-	70	
Break-before-make time [e]	t_{BBM}	$V_{S(all)}$ = V_{DA} = 3.5 V see fig. 4		Room	1	13	-	
				Full	-	-	-	
Enable turn-on time [e]	$t_{ON(\overline{EN})}$	V_{AX} = 0 V, V_{S1} = 3.5 V (DG9408E) V_{AX} = 0 V, V_{S1b} = 3.5 V (DG9409E) see fig. 3		Room	-	54	70	
				Full	-	-	76	
Enable turn-off time [e]	$t_{OFF(\overline{EN})}$			Room	-	28	40	
				Full	-	-	43	
Source off capacitance [e]	$C_{S(off)}$	f = 1 MHz, V_S = 0 V, $V_{\overline{EN}}$ = 2 V	DG9408E	Room	-	15	-	pF
			DG9409E	Room	-	14	-	
Drain off capacitance [e]	$C_{D(off)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 2 V	DG9408E	Room	-	126	-	
			DG9409E	Room	-	63	-	
Drain on capacitance [e]	$C_{D(on)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 0 V	DG9408E	Room	-	153	-	
			DG9409E	Room	-	89	-	
Power Supplies								
Power supply current	I+	$V_{\overline{EN}}$ = VA = 0 V or V+		Room	-	-	1	µA
	I-			Room	-1	-	-	

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

SPECIFICATIONS (Single Supply 5 V)								
PARAMETER	**SYMBOL**	**TEST CONDITIONS UNLESS OTHERWISE SPECIFIED** V+ = 5 V, ± 10 %, V- = 0 V V_A, $V_{\overline{EN}}$ = 0.8 V or 2 V [f]		**TEMP.** [b]	**LIMITS -40 °C to +85 °C**			**UNIT**
					MIN. [c]	**TYP.** [d]	**MAX.** [c]	
Analog Switch								
Analog signal range [e]	V_{ANALOG}			Full	0	-	5	V
On-resistance	R_{ON}	V+ = 4.5 V, V_D or V_S = 1 V or 3.5 V, I_S = 50 mA		Room	-	6.8	10.5	Ω
				Full	-	-	11	
R_{ON} match between channels [g]	ΔR_{ON}	V+ = 4.5 V, V_D = 1 V or 3.5 V, I_S = 50 mA		Room	-	-	3.6	
On-resistance flatness [i]	R_{ON} Flatness			Room	-	-	9	
Switch off leakage current [a]	$I_{S(off)}$	V+ = 5.5 V V_S = 1 V or 4 V, V_D = 4 V or 1 V		Room	-2	-	2	nA
				Full	-15	-	15	
	$I_{D(off)}$			Room	-2	-	2	
				Full	-15	-	15	
Channel on leakage current [a]	$I_{D(on)}$	V+ = 5.5 V V_D = V_S = 1 V or 4 V, sequence each switch on		Room	-2	-	2	
				Full	-15	-	15	
Digital Control								
Logic high input voltage	V_{INH}	V+ = 5 V		Full	2	-	-	V
Logic low input voltage	V_{INL}			Full	-	-	0.8	
Input current [a]	I_{IN}	V_{AX} = $V_{\overline{EN}}$ = 2 V or 0.8 V		Full	-1	-	1	µA
Dynamic Characteristics								
Transition time [e]	t_{TRANS}	V_{S1} = 3.5 V, V_{S8} = 0 V, (DG9408E) V_{S1b} = 3.5 V, V_{S4b} = 0 V, (DG9409E) see fig. 2		Room	-	79	97	ns
				Full	-	-	112	
Break-before-make time [e]	t_{OPEN}	$V_{S(all)}$ = V_{DA} = 3.5 V see fig. 4		Room	2	35	-	
				Full	-	-	-	
Enable turn-on time [e]	$t_{ON(\overline{EN})}$	V_{AX} = 0 V, V_{S1} = 3.5 V (DG9408E) V_{AX} = 0 V, V_{S1b} = 3.5 V (DG9409E) see fig. 3		Room	-	83	95	
				Full	-	-	116	
Enable turn-off time [e]	$t_{OFF(\overline{EN})}$			Room	-	36	57	
				Full	-	-	61	
Charge injection [e]	Q	C_L = 1 nF, R_{GEN} = 0, V_{GEN} = 0 V		Room	-	3.7	-	pC
Off isolation [e, h]	OIRR	R_L = 1 kΩ, f = 100 kHz		Room	-	-83	-	dB
Crosstalk [e]	X_{TALK}			Room	-	-90	-	
Source off capacitance [e]	$C_{S(off)}$	f = 1 MHz, V_S = 0 V, $V_{\overline{EN}}$ = 0 V	DG9408E	Room	-	19	-	pF
			DG9409E	Room	-	18	-	
Drain off capacitance [e]	$C_{D(off)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 2 V	DG9408E	Room	-	149	-	
			DG9409E	Room	-	74	-	
Drain on capacitance [e]	$C_{D(on)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 0 V	DG9408E	Room	-	170	-	
			DG9409E	Room	-	94	-	
Power Supplies								
Power supply current	I+	$V_{\overline{EN}}$ = V_A = 0 V or V+		Room	-	-	1	µA

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

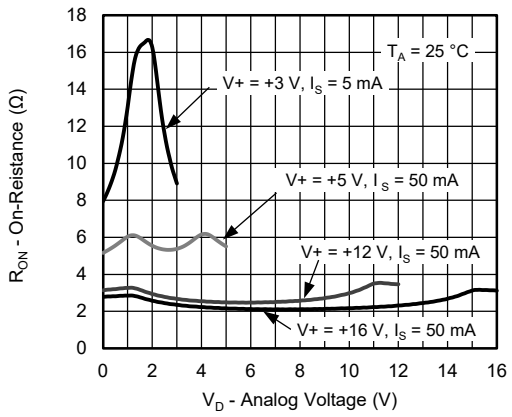
SPECIFICATIONS (Single Supply 3 V)								
PARAMETER	**SYMBOL**	**TEST CONDITIONS UNLESS OTHERWISE SPECIFIED** V+ = 3 V, ± 10 %, V- = 0 V $V_{\overline{EN}}$ = 0.4 V or 1.8 V [f]		**TEMP.** [b]	**LIMITS -40 °C to +85 °C**			**UNIT**
					MIN. [c]	**TYP.** [d]	**MAX.** [c]	
Analog Switch								
Analog signal range [e]	V_{ANALOG}			Full	0	-	3	V
On-resistance	R_{ON}	V+ = 2.7 V, V_D = 0.5 V or 2.2 V, I_S = 5 mA		Room	-	13	25.5	Ω
				Full	-	-	26.5	
R_{ON} match between channels [g]	ΔR_{ON}	V+ = 2.7 V, V_D = 0.5 V or 2.2 V, I_S = 5 mA		Room	-	-	3.6	
On-resistance flatness [i]	R_{ON} Flatness			Room	-	-	13	
Switch off leakage current [a]	$I_{S(off)}$	V+ = 3.3 V V_S = 2 V or 1 V, V_D = 1 or 2 V		Room	-2	-	2	nA
				Full	-15	-	15	
	$I_{D(off)}$			Room	-2	-	2	
				Full	-15	-	15	
Channel on leakage current [a]	$I_{D(on)}$	V+ = 3.3 V V_D = V_S = 1 V or 2 V, sequence each switch on		Room	-2	-	2	
				Full	-15	-	15	
Digital Control								
Logic high input voltage	V_{INH}			Full	1.8	-	-	V
Logic low input voltage	V_{INL}			Full	-	-	0.4	
Input current [a]	I_{IN}	V_{AX} = $V_{\overline{EN}}$ = 1.8 V or 0.4 V		Full	-1	-	1	µA
Dynamic Characteristics								
Transition time	t_{TRANS}	V_{S1} = 1.5 V, V_{S8} = 0 V, (DG9408E) V_{S1b} = 1.5 V, V_{S4b} = 0 V, (DG9409E) see fig. 2		Room	-	169	245	ns
				Full	-	-	278	
Break-before-make time	t_{BBM}	$V_{S(all)}$ = V_{DA} = 1.5 V see fig. 4		Room	2	96	-	
				Full	-	-	-	
Enable turn-on time	$t_{ON(\overline{EN})}$	V_{AX} = 0 V, V_{S1} = 1.5 V (DG9408E) V_{AX} = 0 V, V_{S1b} =1.5 V (DG9409E) see fig. 3		Room	-	202	255	
				Full	-	-	272	
Enable turn-off time	$t_{OFF(\overline{EN})}$			Room	-	72	97	
				Full	-	-	104	
Charge injection [e]	Q	C_L = 1 nF, R_{GEN} = 0, V_{GEN} = 0 V		Room	-	2.1	-	pC
Off isolation [e, h]	OIRR	f = 100 kHz, R_L = 1 kΩ		Room	-	-83	-	dB
Crosstalk [e]	X_{TALK}			Room	-	-90	-	
Source off capacitance [e]	$C_{S(off)}$	f = 1 MHz, V_S = 0 V, $V_{\overline{EN}}$ = 1.8 V	DG9408E	Room	-	20	-	pF
			DG9409E	Room	-	19	-	
Drain off capacitance [e]	$C_{D(off)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 1.8 V	DG9408E	Room	-	159	-	
			DG9409E	Room	-	79	-	
Drain on capacitance [e]	$C_{D(on)}$	f = 1 MHz, V_D = 0 V, $V_{\overline{EN}}$ = 0 V	DG9408E	Room	-	179	-	
			DG9409E	Room	-	98	-	
Power Supplies								
Power supply current	I+	$V_{\overline{EN}}$ = V_A = 0 V or V+		Room	-	-	1	µA

Notes

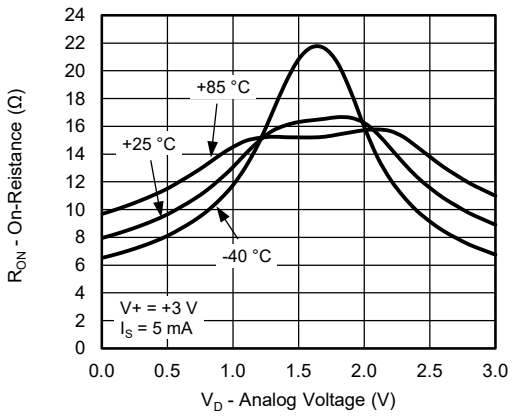
a. Leakage parameters are guaranteed by worst case test condition and not subject to production test
b. Room = 25 °C, full = as determined by the operating temperature suffix
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
e. Guaranteed by design, not subject to production test
f. V_{IN} = input voltage to perform proper function
g. ΔR_{DON} = R_{DON} max. - R_{DON} min
h. Worst case isolation occurs on channel 4 due to proximity to the drain pin
i. R_{DON} flatness is measured as the difference between the minimum and maximum measured values across a defined analog signal

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

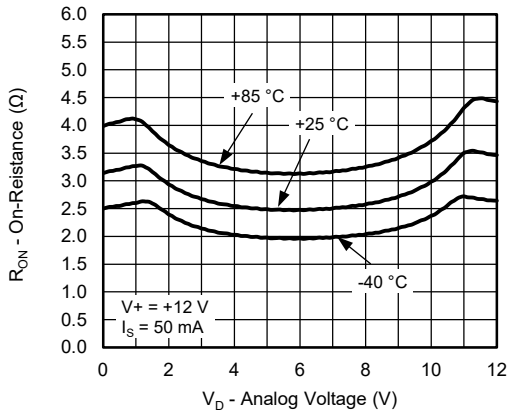
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



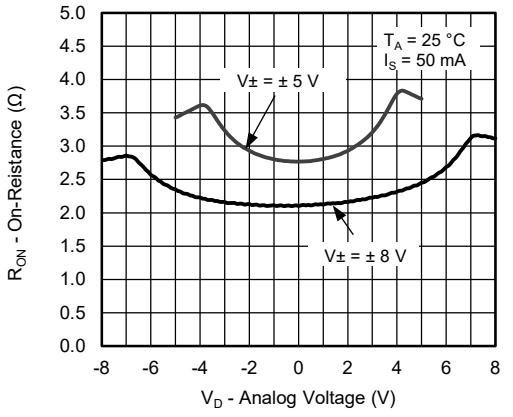
On-Resistance vs. Analog Voltage



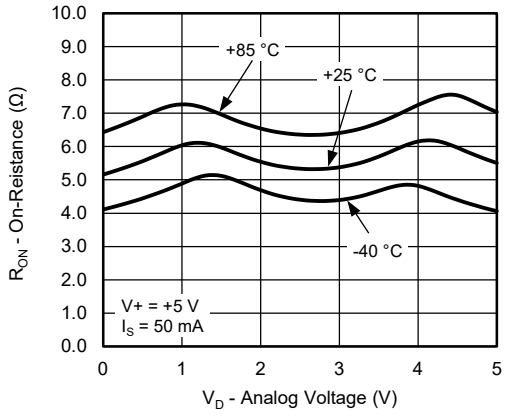
On-Resistance vs. Analog Voltage



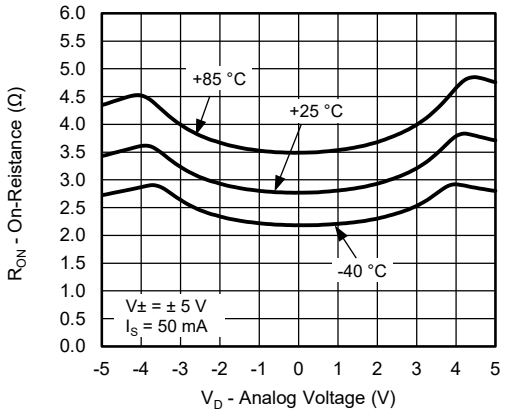
On-Resistance vs. Analog Voltage



On-Resistance vs. Analog Voltage



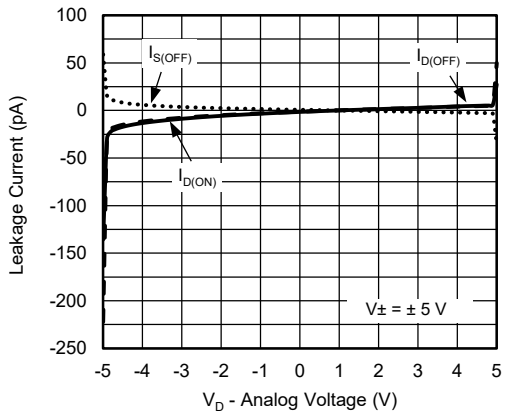
On-Resistance vs. Analog Voltage



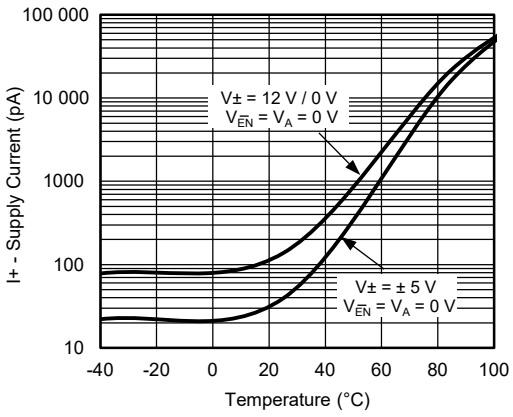
On-Resistance vs. Analog Voltage

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

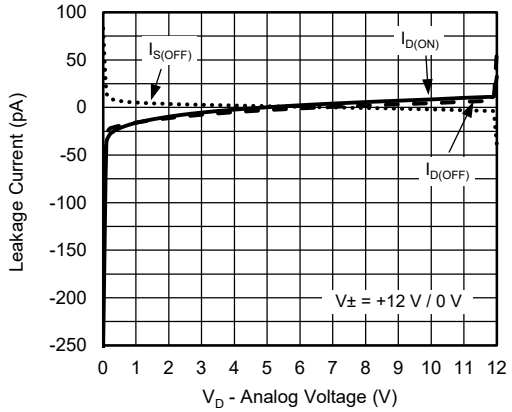
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



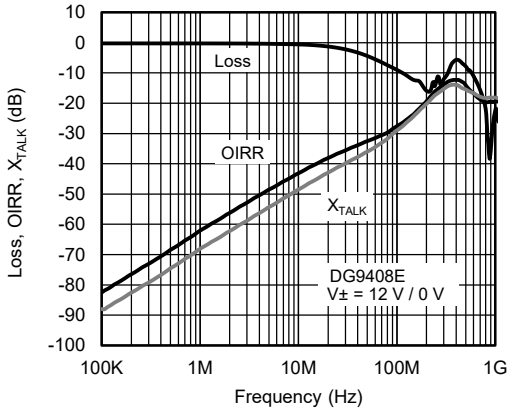
Leakage Current vs. Analog Voltage



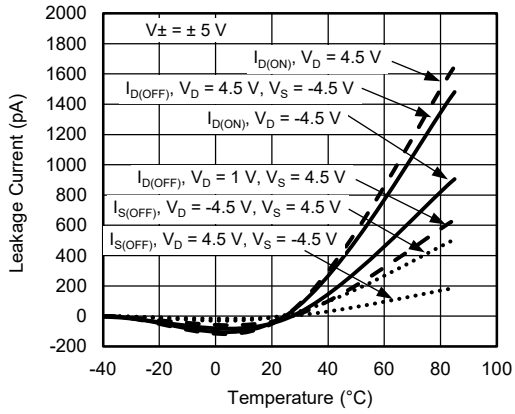
Supply Current vs. Temperature



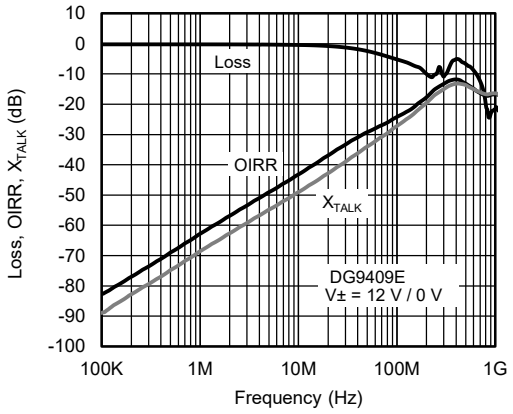
Leakage Current vs. Analog Voltage



Loss, OIRR, X_{TALK} vs. Frequency



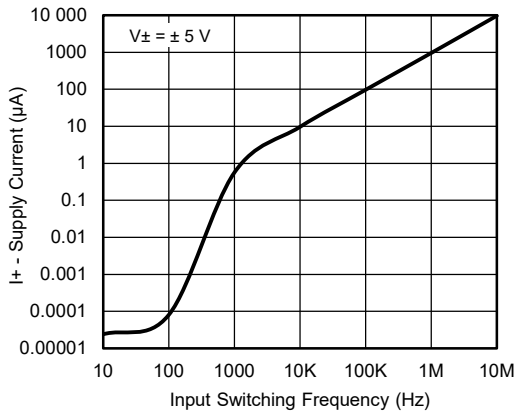
Leakage Current vs. Temperature



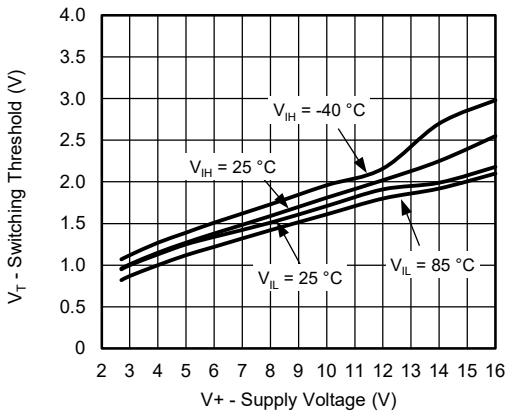
Loss, OIRR, X_{TALK} vs. Frequency

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

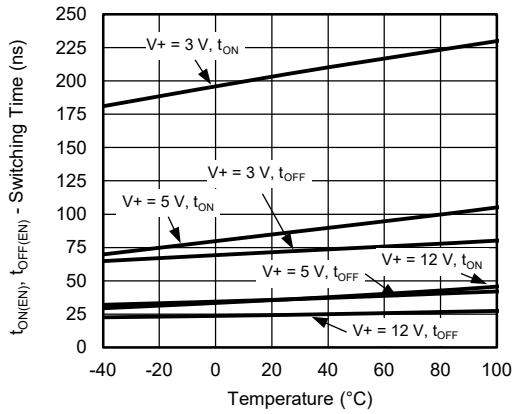
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



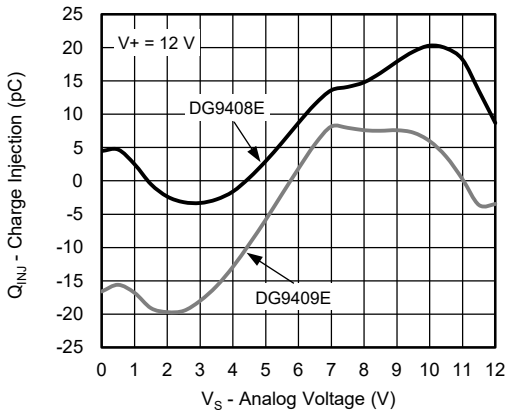
Supply Current vs. Input Switching Frequency



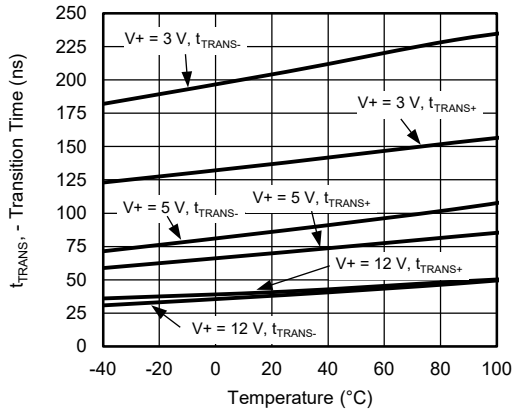
Switching Threshold vs. Supply Voltage



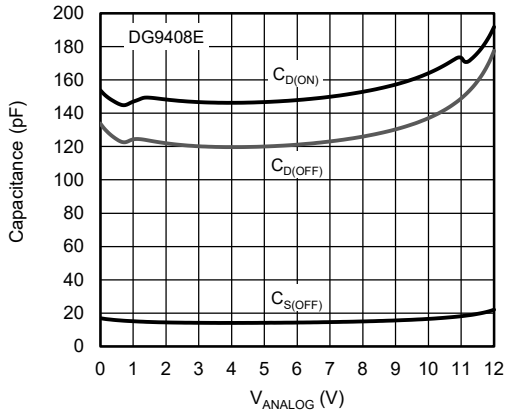
Switching Time vs. Temperature



Charge Injection vs. Analog Voltage



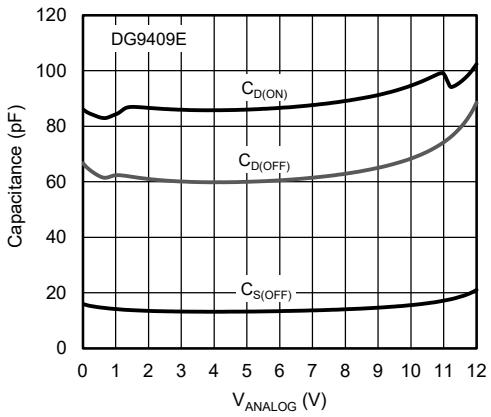
Transition Time vs. Temperature



Capacitance vs. Analog Voltage

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Capacitance vs. Analog Voltage

SCHEMATIC DIAGRAM (Typical channel)

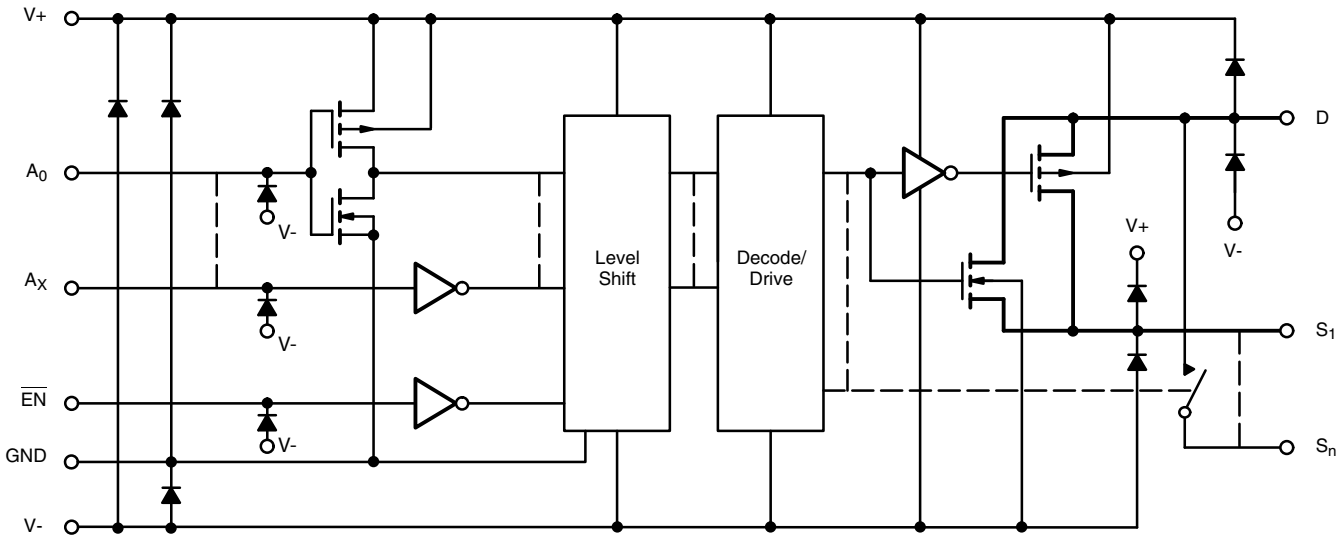
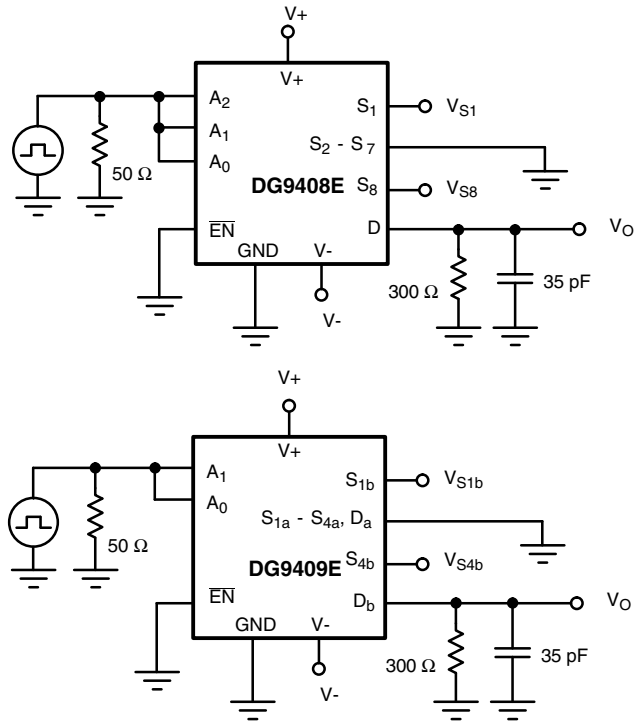
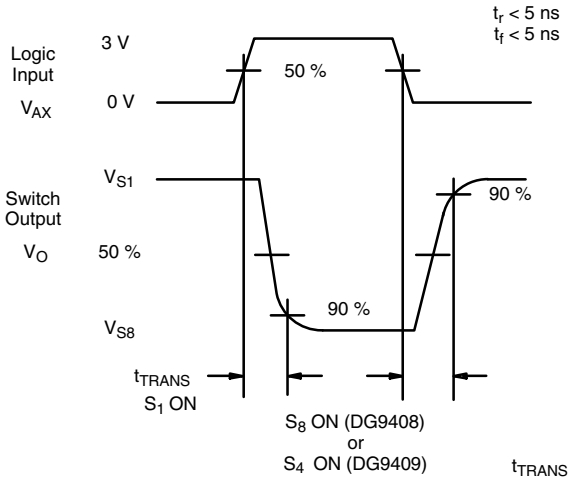


Fig. 1 -

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

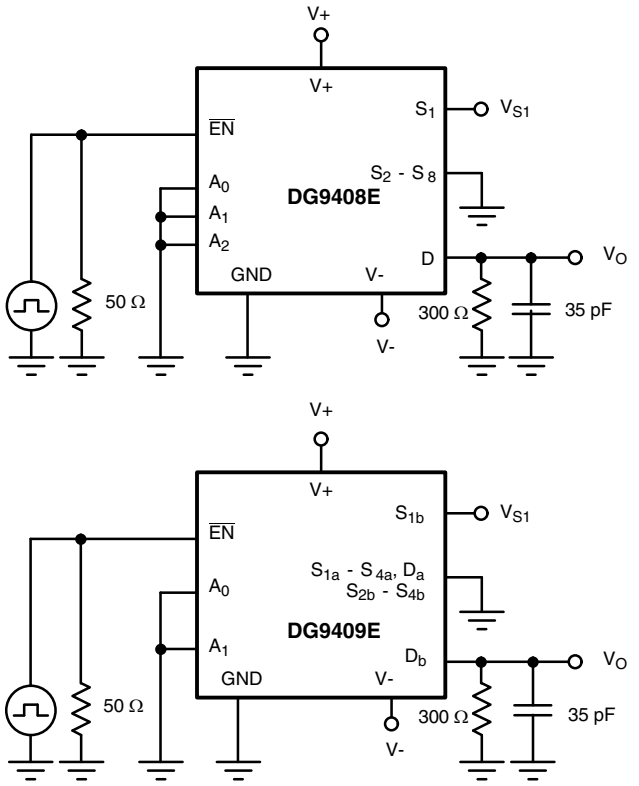
TEST CIRCUITS

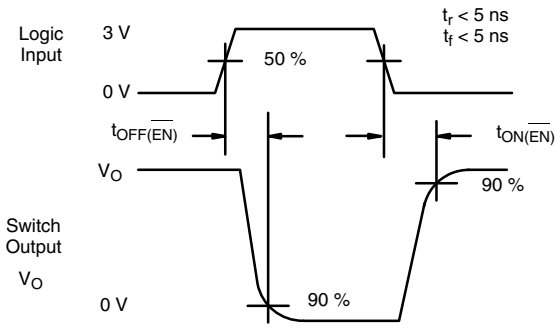




Return to Specifications:
Single Supply 12 V
Dual Supply V+ = 5 V, V- = - 5 V
Single Supply 5 V
Single Supply 3 V

Fig. 2 - Transition Time



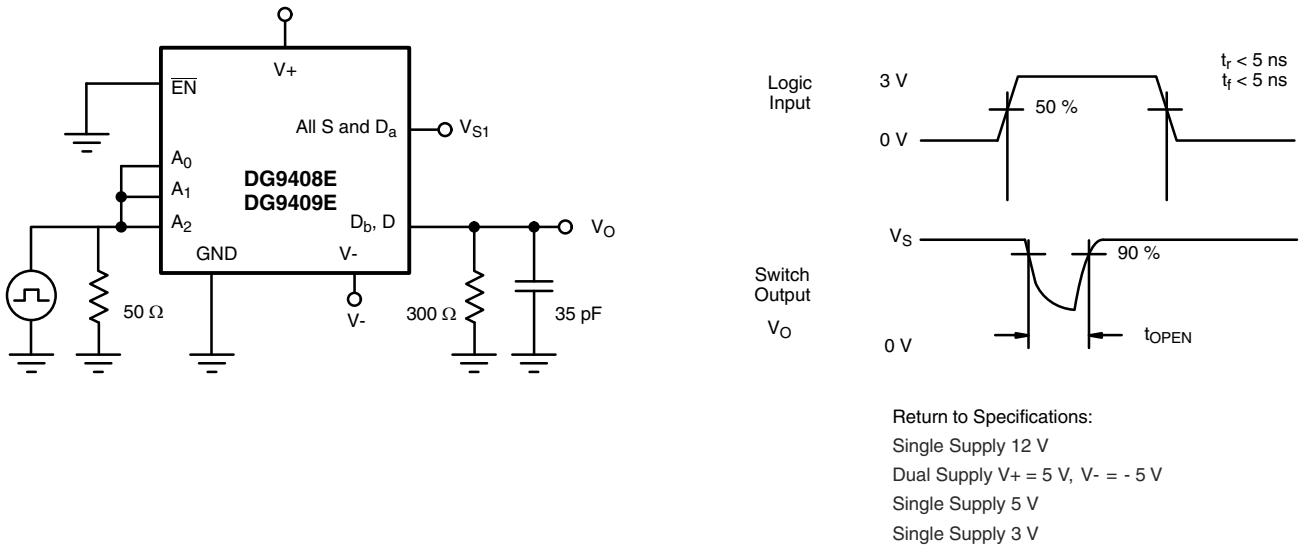


Return to Specifications:
Single Supply 12 V
Dual Supply V+ = 5 V, V- = - 5 V
Single Supply 5 V
Single Supply 3 V

Fig. 3 - Enable Switching Time

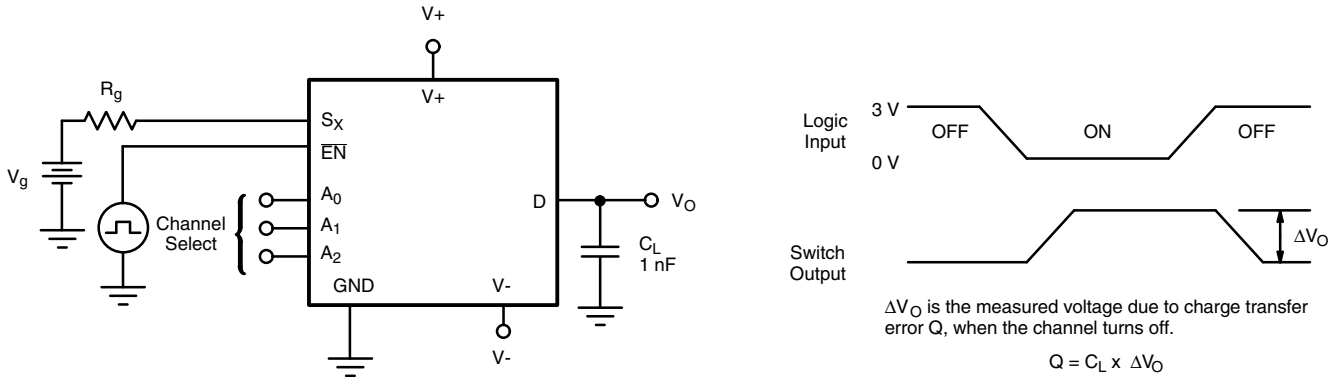
For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TEST CIRCUITS



Return to Specifications:
Single Supply 12 V
Dual Supply V+ = 5 V, V- = - 5 V
Single Supply 5 V
Single Supply 3 V

Fig. 4 - Break-Before-Make Interval



ΔV_O is the measured voltage due to charge transfer error Q, when the channel turns off.

$$Q = C_L \times \Delta V_O$$

Fig. 5 - Charge Injection

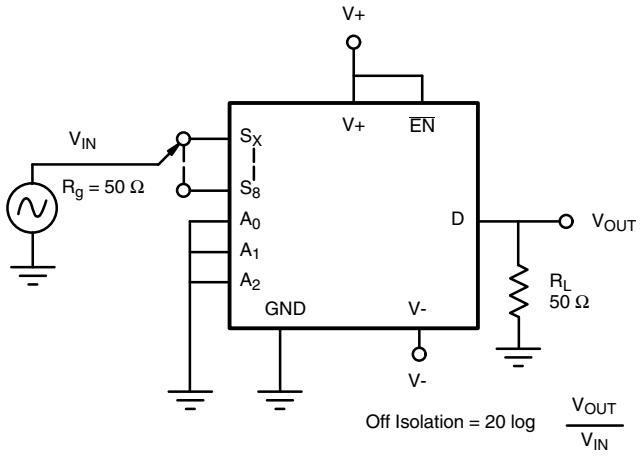


Fig. 6 - Off Isolation

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TEST CIRCUITS

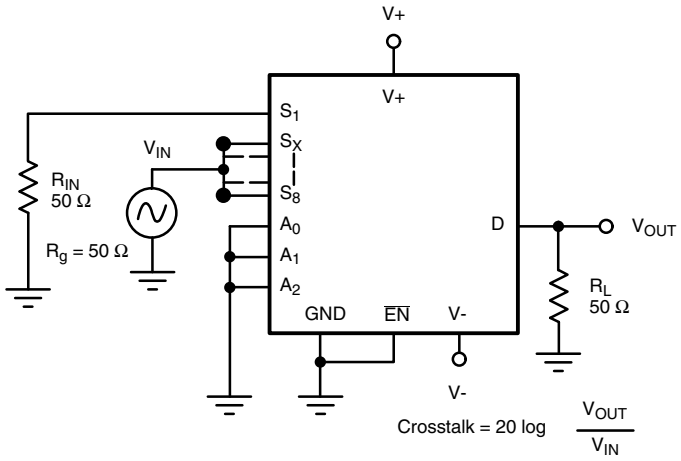


Fig. 7 - Crosstalk

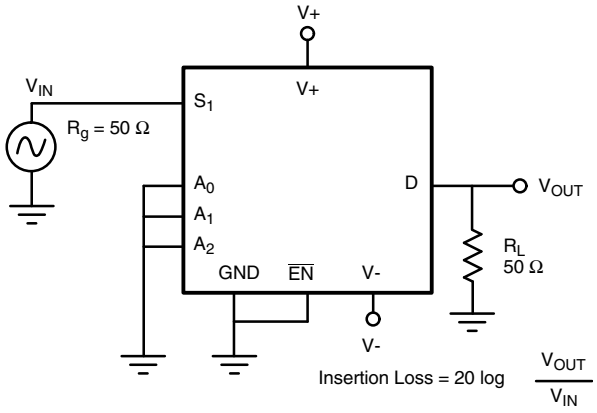


Fig. 8 - Insertion Loss

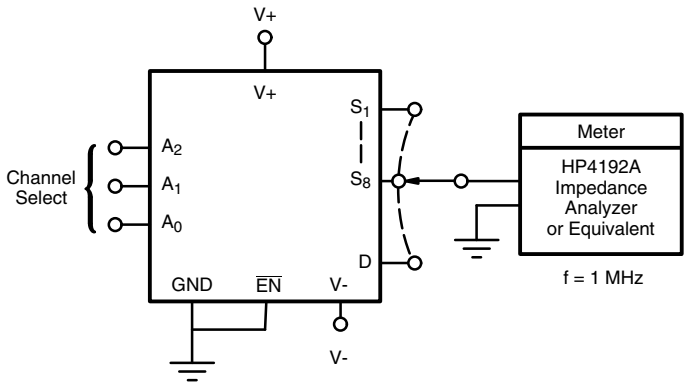


Fig. 9 - Source Drain Capacitance

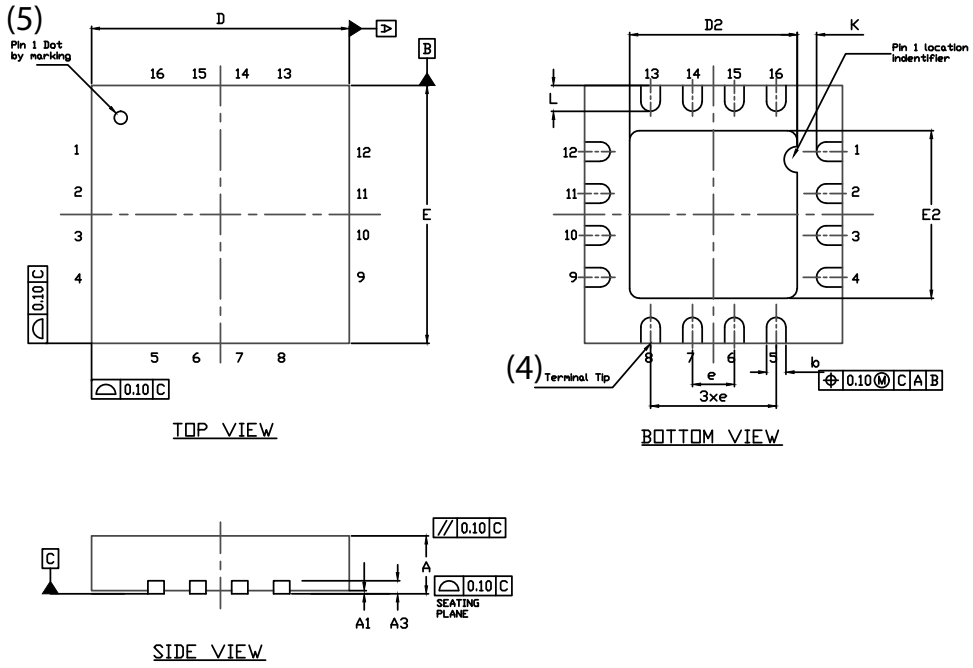
For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

PRODUCT SUMMARY		
Part number	DG9408E	DG9409E
Status code	2	2
Configuration	8:1 x 1	4:1 x 2
Single supply min. (V)	3	3
Single supply max. (V)	16	16
Dual supply min. (V)	3	3
Dual supply max. (V)	8	8
On-resistance (Ω)	3.2	3.2
Charge injection (pC)	4.5	4.5
Source on capacitance (pF)	154	86
Source off capacitance (pF)	17	16
Leakage switch on typ. (nA)	-	-
Leakage switch off max. (nA)	2	2
-3 dB bandwidth (MHz)	-	-
Package	QFN-16 4 x 4	QFN-16 4 x 4
Functional circuit / applications	Multi Purpose, instrumentation, medical and healthcare, portable	Multi Purpose, instrumentation, medical and healthcare, portable
Interface	Binary	Binary
Single supply operation	Yes	Yes
Dual supply operation	Yes	Yes
Turn on time max. (ns)	71	71
Crosstalk and off isolation	-83	-83

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75375.

For technical questions, contact: analogswitchtechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

QFN 4x4-16L Case Outline



DIM	VARIATION 1						VARIATION 2					
	MILLIMETERS[1]			INCHES			MILLIMETERS[1]			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
A3	0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.		
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.012	0.014
D	4.00 BSC			0.157 BSC			4.00 BSC			0.157 BSC		
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
e	0.65 BSC			0.026 BSC			0.65 BSC			0.026 BSC		
E	4.00 BSC			0.157 BSC			4.00 BSC			0.157 BSC		
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
K	0.20 min.			0.008 min.			0.20 min.			0.008 min.		
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020
N[3]	16			16			16			16		
Nd[3]	4			4			4			4		
Ne[3]	4			4			4			4		

Notes

(1) Use millimeters as the primary measurement.
(2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
(3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
(4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
(5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
(6) Package warpage max. 0.05 mm.

ECN: S13-0893-Rev. B, 22-Apr-13
DWG: 5890

For technical questions, contact: powerictechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2026 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000